

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: William G. America

Conf. No.: 3775

Serial No.: 10/709,776

Art Unit: 2811

Filed: 05/27/2004

Examiner: Im, Junghwa M.

Title: SEMICONDUCTOR DEVICE FORMED
BY IN-SITU MODIFICATION OF
DIELECTRIC LAYER AND RELATED
METHODS

Docket No.: FIS920040083US1
(IBMF-0058)

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REQUEST FOR RECONSIDERATION

Sir:

I. INTRODUCTORY COMMENTS

This paper is being filed in response to the Office Action dated September 12, 2007.

Please reconsider the above-referenced patent application as follows: